

A STUDY ON BROADBAND PHOTODETECTOR BASED ON HYBRID 2D COPPER OXIDE/ REDUCED GRAPHENE OXIDE

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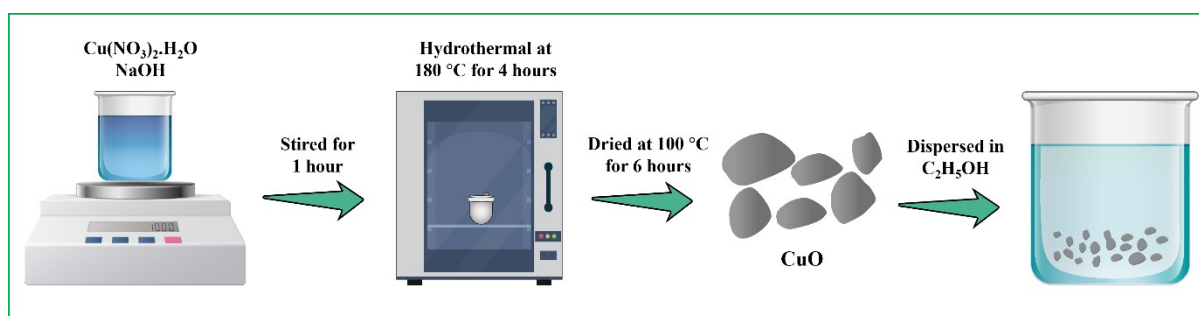


Figure S1. Synthesis process of 2D CuO dispersion.

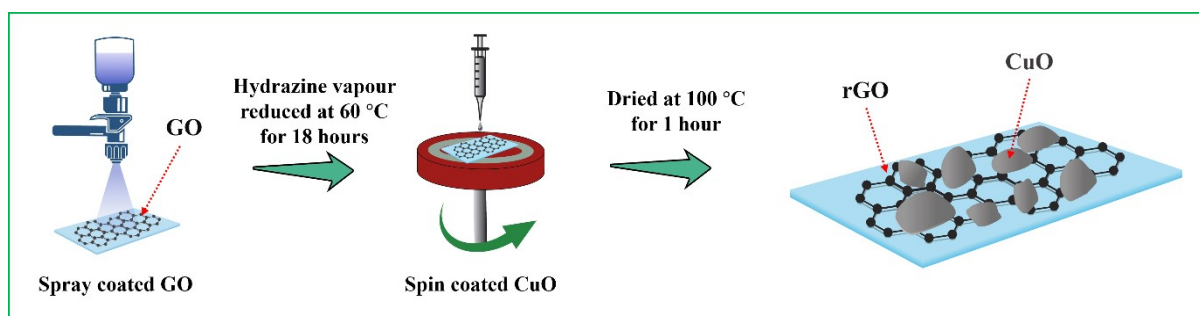


Figure S2. Synthesis process of 2D CuO/rGO hybrid thin film.

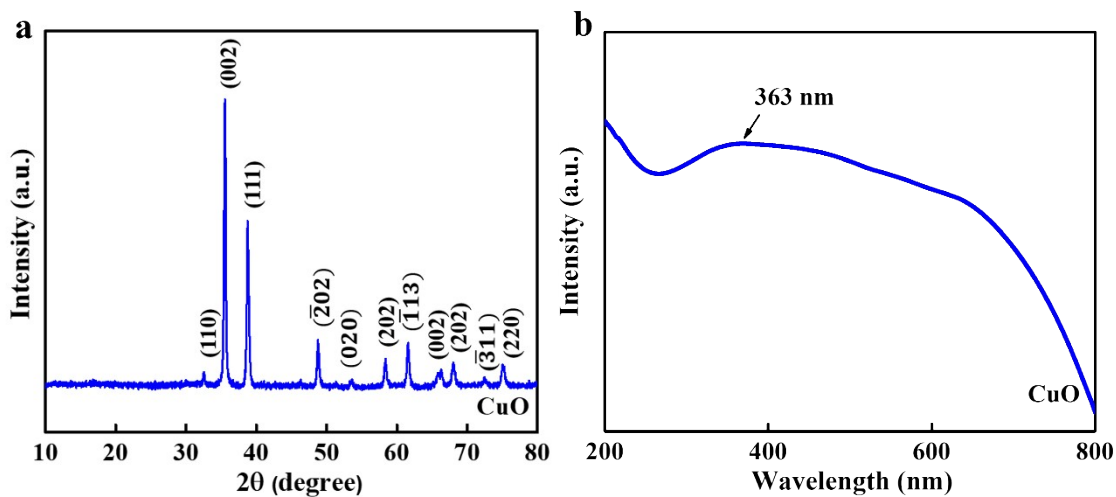


Figure S3. (a) XRD pattern and (b) UV-vis spectrum of 2D CuO sample

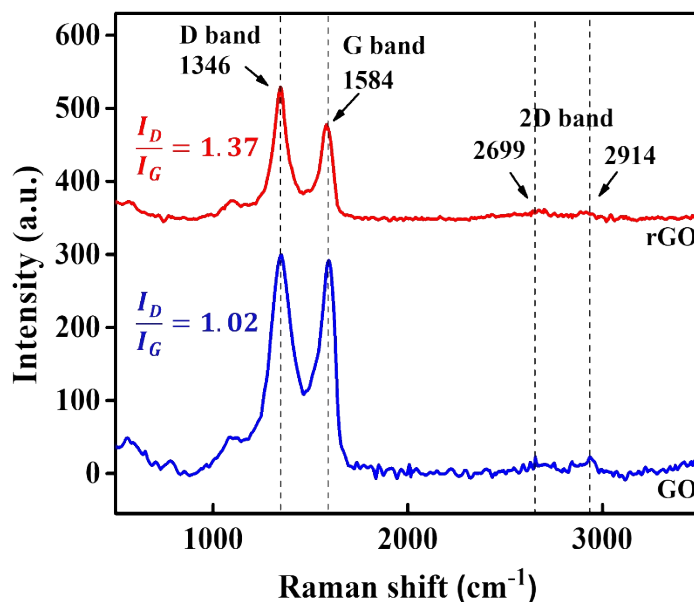


Figure S4. Raman spectra of GO and rGO samples

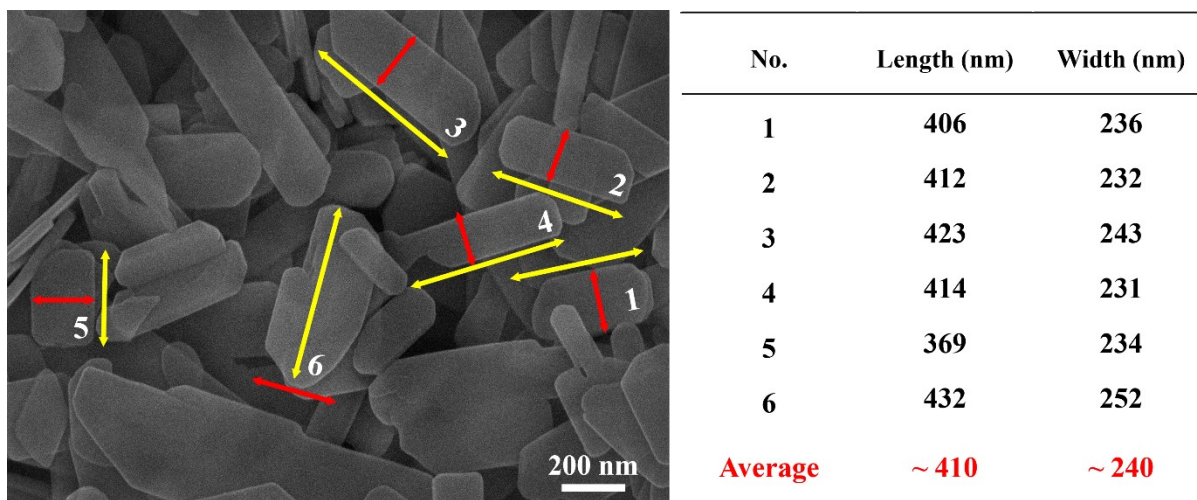


Figure S5. SEM image and size statistics of 2D CuO nanoplates

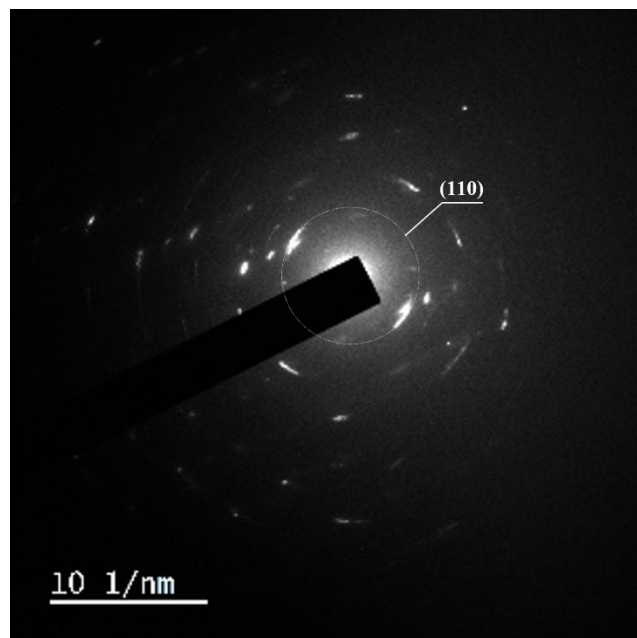


Figure S6. SAED pattern of 2D CuO/rGO

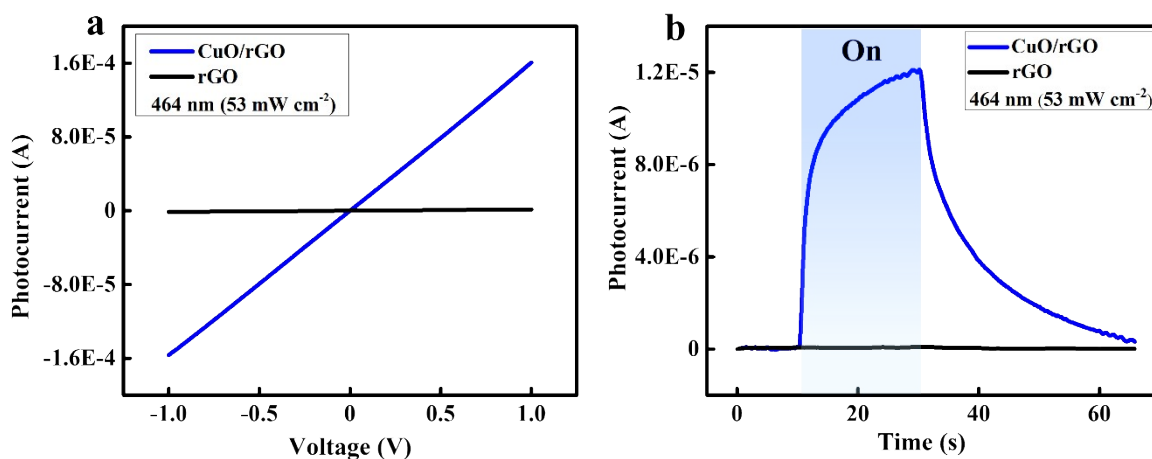


Figure S7. (a) I-V and (b) I-t characteristics of rGO and 2D CuO/rGO photodetectors under 464 nm light

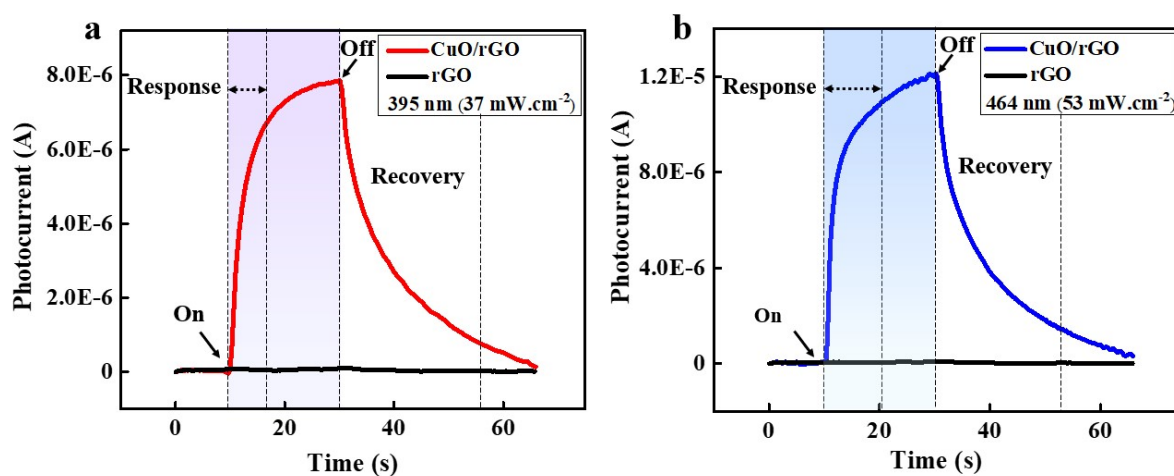


Figure S8. Response and recovery time of a hybrid photodetector under exposure to (a) 395 nm and (b) 464 nm lights

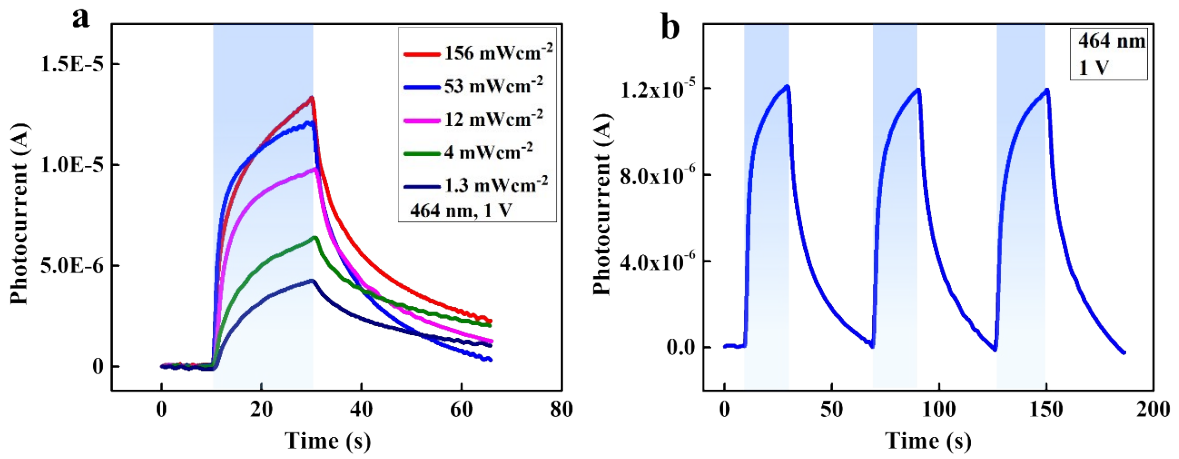


Figure S9. (a) *I*-*t* curves and (b) the repeatability of a hybrid photodetector under 464 nm light

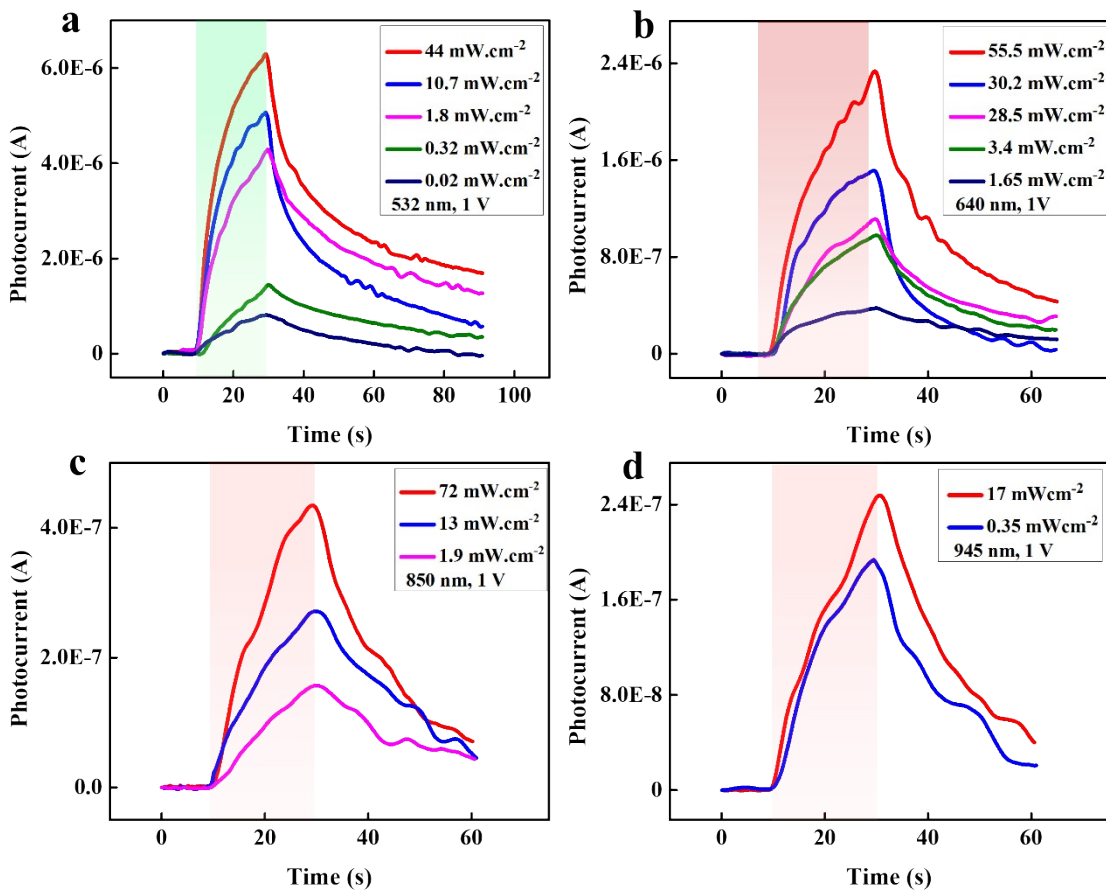


Figure S10. *I*-*t* curves of the hybrid device under exposure to light at wavelengths of (a) 532 nm, (b) 640 nm, (c) 850 nm, and (d) 945 nm.

The hybrid device generated the highest photocurrents of 6.3, 2.3, 0.43, and 0.25 μA when excited by the 532-, 640-, 850-, and 945-nm wavelengths, respectively. When the light was ON, the photocurrent immediately increased, and when the light was OFF, the photocurrent decreased. Notably, it gradually decreased as increasing the light intensity.

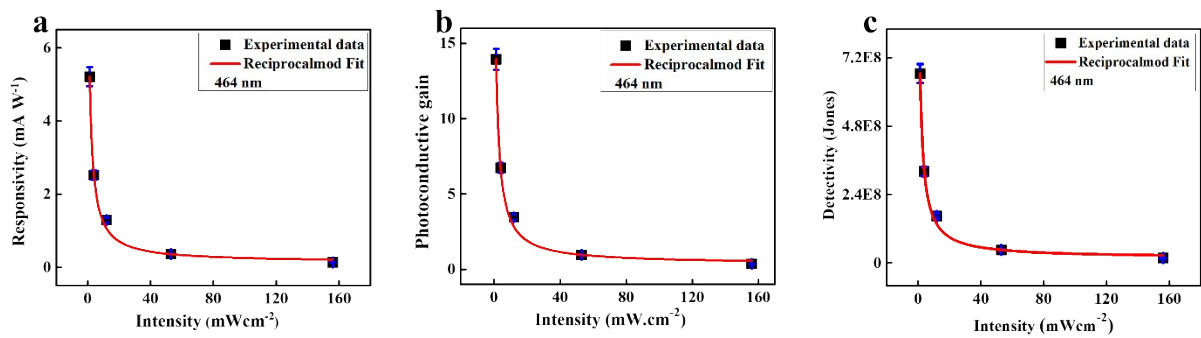


Figure S11. (a) Responsivity, (b) photoconductive gain and (c) detectivity of 2D CuO/rGO device including reciprocal function fitting lines with error bar.